

Analog Photoelectric Sensor

E3SA

Analog Output Proportional to Light Received, Ideal For Inspection and Measurement

- Analog object detection ideal for position, size, color and surface characteristics
- Both analog and NPN transistor ON/OFF outputs available simultaneously
- Fast, 1 ms response time
- Selectable Light-ON/Dark-ON operation
- 4-turn sensitivity adjustment for precise control
- 2 m (6.56 ft) cable



Ordering Information_

SENSORS

Method of detection	Through-beam	Retroreflective	Diffuse reflective	Mark sensor
Sensing distance	2 m (6.56 ft), 30 cm (11.81 in) with E39-S1 slits	20 to 50 cm (7.87 to 19.68 in)	5 to 50 cm (1.97 to 19.68 in)	2 to 5 cm (0.79 to 1.97 in)
Part number	E3SA-2C43A	E3SA-RS50C43A	E3SA-DS50C43A	E3SA-VS5RC43A

ACCESSORIES

Description	Part number
Slits for E3SA-2C43A through-beam type help detect transparent and small objects	E39-S1
(0.5, 1, 2 and 4 mm slits; mounting hardware)	

■ REPLACEMENT PARTS

Description	Part number
Reflector (supplied with E3SA-RS50C43A retroreflective sensor)	E39-R1
Mounting bracket (supplied with each sensor)	E39-L52

Specifications _____

Method of detection Through-beam Retroreflective Diffuse reflective Mark sensor Supply voltage 12 to 24 VDC Diffuse reflective Mark sensor Current consumption Emitter: 60 mA max. Receiver: 20 mA max. 80 mA max. Receiver: 20 mA max. 80 mA max. Sensing distance 2 m (6.56 ft) 30 cm (11.81 in) with E39-S1 slits 20 to 50 cm (7.87 to 19.68 in) with E39-S1 slits 5 to 50 cm (1.97 to 19.68 in) with 10 x 10 cm (3.94 x 3.94 in) with 23 y A x 3.94 in) with 23 y A x 3.94 in) with 8 a y A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A x 3.94 in) with 9 a to 2 w A with 3 0 Ω max. Ioad impedance; 2.45 to 4 mA minimum, 20 to 21.55 mA maximum 1 to 5 VDC using 250 Ω resistor supplied. See "Connections" for conversion. Operating point Adjustable; 4-turn potentiometer Operation work in 30 Ω max. Ioad impedance; 2.45 to 4 mA minimum, 20 to 21.55 mA maximum 1 to 5 VDC using 250 Ω resistor supplied. See "Connections" for conversion.
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Circuit Output short- Provided circuit Provided
DC power supply Provided reverse polarity
Indicators Emitter: Light Incident (red LED) Power On (red LED) Receiver: Light Incident (red LED) Output Operation (yellow LED)
Materials Lens Plastic
Case Plastic
Cable sheath Plastic
Mounting Side surface mount with two through holes. E39-L52 bracket and mounting hardware supplied.
Connections Prewired Emitter: 2-conductor cable, 2 m (6.56 ft) length Receiver: 5-conductor cable, 2 m (6.56 ft) length 4-conductor cable, 2 m (6.56 ft) length
Weight Emitter: 140 g (5 oz) Receiver: 140 g (5 oz) 140 g (5 oz)
Enclosure IEC 144 IP66
Ambient Operating -10°C to 55°C (14°F to 131°F)
temperature Storage -30°C to 70°C (-22°F to 159°F)

OUTPUT CIRCUIT DIAGRAM

Through-Beam Type E3SA-2C43A



Polarized Retroreflective Type E3SA-RS50C43A Diffuse Reflective Type E3SA-DS50C43A Mark Sensor E3SA-VS5RC43A Fiber-Optic Amplifier E3XA-CC4A



Note: IEC colors are shown in parentheses.

TIMING CHARTS

Through-Beam Type E3SA-2C43A

High Input light quantity î Lov F External check input (light source) (receiver) 20 mA Analog output Logic output Threshold level 4 mA ON L-ON (output transistor) OFF Logic output D-ON ON (output transistor) OFF

Note: The light source operates (ON) when the external check input is open; it does not operate (OFF) when the external check input is ON (Low).

Polarized Retroreflective Type E3SA-RS50C43A Diffuse Reflective Type E3SA-DS50C43A Mark Sensor E3SA-VS5RC43A Fiber-Optic Amplifier E3XA-CC4A



Connections



Note: IEC colors are shown in parentheses.

For voltage output (1 to 5 VDC)

To convert current output into voltage output (1 to 5 VDC), use the 250-ohm resistor, supplied with the sensor.



Engineering Data _____

OPERATING RANGE

Through-Beam Type E3SA-2C43A without slit



Polarized Retroreflective Type E3SA-RS50C43A



5

Diffuse Reflective Type E3SA-DS50C43A



0

Through-Beam Type

DISTANCE vs. ANALOG OUTPUT CURRENT

Through-Beam Type E3SA-2C43A without slit



Polarized Retroreflective Type E3SA-RS50C43A



Diffuse Reflective Type E3SA-DS50C43A (white object)

Rated sensing distance

2

3

Sensing distance (m)

4

5

6



Diffuse Reflective Type E3SA-DS50C43A (black object)



Mark Sensor Type E3SA-VSRC43A



OBJECT SIZE vs. OUTPUT

Diffuse Reflective Type E3SA-DS50C43A



Diffuse Reflective Type E3SA-DS50C43A



Mark Sensor Type E3SA-VSRC43A



Polarized Retroreflective Type E3SA-RS50C43A



■ LIGHT INTERRUPTING CHARACTERISTICS

Through-Beam Type E3SA-2C43A Without Slit, in Y Direction



Through-Beam Type E3SA-2C43A Without Slit, in X Direction



⁽Optical axis position) Moving distance of sensing object $\ell \pmod{\ell}$

Through-Beam Type E3SA-2C43A With Slit, in Y Direction



Through-Beam Type E3SA-2C43A With Slit, in X Direction





MUTUAL INTERFERENCE

If sensors are installed side by side, provide at least the minimum distance shown in the shaded region of the following charts between sets of fibers to prevent mutual interference.



Through-Beam Type E3SA-2C43A Without Slit



Sensing distance X (cm)

Fluorescent

Angle of sensor in respect to fluorescent lamp $\varphi = 0^{\circ}$

Through-Beam Type E3SA-2C43A With Slit



■ INFLUENCE OF EXTERNAL LIGHT INTERFERENCE



Distance from fluorescent lamp ℓ (m)

Diffuse Reflective Type E3SA-DS50C43A



Distance from fluorescent lamp $\ell \ \ (m)$

Through-Beam Type

2.5

2.0

1.5

1.0

0.

0.15 mA

Analog output ripple current (mA)

E3SA-2C43A With Slit



Retroreflective Type E3SA-RS50C43A



Distance from fluorescent lamp ℓ (cm)

Diffuse Reflective Type

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TRANSPARENCY AND COLOR vs. ANALOG OUTPUT

Through-Beam Type E3SA-2C43A Without Slit



COLOR MARK DETECTION CAPABILITY





Diffuse Reflective Type E3SA-DS5C43A



Dimensions



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E3SA =

Retroreflective Type E3SA-RS50C43A (included E39-R1 reflector) Diffuse Reflective Type E3SA-DS50C43A Mark Sensor E3SA-VS5RC43A



REFLECTORS

E39-R1 Reflector supplied with each E3SA-RS50C43A Retroreflective Sensor



Operation

■ NOMENCLATURE



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For Through-Beam and Retroreflective Sensors

Using Indication:

Mount the emitter or reflector, then loosely mount the receiver. Aim the receiver to get the maximum brightness on the Light Indicator. Adjust the Sensitivity Control (gain) to maximize the brightness. Then securely mount the receiver to maintain the position.

Using Analog Output:

Use an ammeter to measure the milliamp current output from the sensor. Mount the emitter or reflector, then loosely mount the receiver. Aim the receiver to get the maximum analog output (20 mA). Move the receiver up and down, left to right to determine the area that produces maximum output. Aim the receiver in the center of that area then securely mount the receiver to maintain the position. Adjust the gain using the Sensitivity Control to produce 20 mA or the desired maximum current output.

To ensure proper adjustment for best sensitivity, be certain that the current has not become saturated above the 20 mA maximum limit. This makes normal detection impossible because the deviation of output at saturation becomes too small for differentiation.

The Easy Method:

The simple way is to use the Operation Point control. Set the operating point at 20 mA (fully clockwise), then search for the position that turns on the Operation Indicator.

For Diffuse Reflective Sensors

Using Indication:

Securely mount the diffuse reflective or mark detecting sensor, or diffuse reflective fiber-optic sensing head. Place the object to be detected at the position where detection should occur. Adjust the Sensitivity Control (gain) to the point where the Operation Indicator lights. Then fine-tune the gain to maximize the brightness of the Light Indicator.

Using Analog Output:

Securely mount the diffuse reflective or mark detecting sensor, or diffuse reflective fiber-optic sensing head. Use an ammeter to measure the milliamp output from the sensor or E3XA amplifier. Place the object to be detected at the position where detection should occur. Adjust the gain using the Sensitivity Control to produce 20 mA or the desired maximum current output.

To ensure proper adjustment for best sensitivity, be certain that the current has not become saturated above the 20 mA maximum limit. This makes normal detection impossible because the deviation of output at saturation becomes too small for differentiation.

■ INFLUENCE OF FLUORESCENT LIGHTING

Do not allow direct exposure of fluorescent light on the receiver (through-beam types) or emitter/receiver (reflective types). This may have adverse affects on the analog output current.

When mounting the sensor, keep the angle formed between the light of the fluorescent lamp and the optical axis of the sensor at more than 15 degrees.



INCORRECT



■ AMPLIFIER OUTPUTS

Analog Output

Set the analog output by allowing a hysteresis of more than 2% full scale (about 0.3 mA), also taking into account the effects of external fluctuations. This effect is already taken into account when using S3A-D and S3A2 analog sensor controllers.

Logic (On/Off) Output

Emitte

The differential for the discrete On/Off logic output is set at about 2 mA. Output short-circuit protection is provided.

F004	
E3SA	E3SA



Cat. No. CEDSAX4

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